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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





BC817-25
BC817-40

SMALL SIGNAL NPN TRANSISTORS

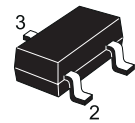
PRELIMINARY DATA

Type	Marking
BC817-25	6B
BC817-40	6C

- SILICON EPITAXIAL PLANAR NPN TRANSISTORS
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE PNP COMPLEMENTARY TYPES ARE BC807-25 AND BC817-40 RESPECTIVELY

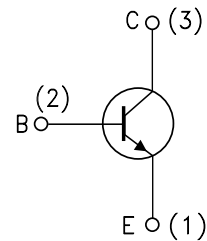
APPLICATIONS

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTORS WITH HIGH GAIN AND LOW SATURATION VOLTAGE



SOT-23

INTERNAL SCHEMATIC DIAGRAM



DS10130

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CB0}	Collector-Base Voltage ($I_E = 0$)	50	V
V_{CE0}	Collector-Emitter Voltage ($I_B = 0$)	45	V
V_{EB0}	Emitter-Base Voltage ($I_C = 0$)	5	V
I_C	Collector Current	0.5	A
I_{CM}	Collector Peak Current	1	A
P_{tot}	Total Dissipation at $T_C = 25\text{ }^\circ\text{C}$	250	mW
T_{stg}	Storage Temperature	-65 to 150	$^\circ\text{C}$
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$

BC817-25 / BC817-40

THERMAL DATA

$R_{thj-amb}$	Thermal Resistance Junction-Ambient	Max	500	$^{\circ}\text{C}/\text{W}$
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• Device mounted on a PCB area of 1 cm^2

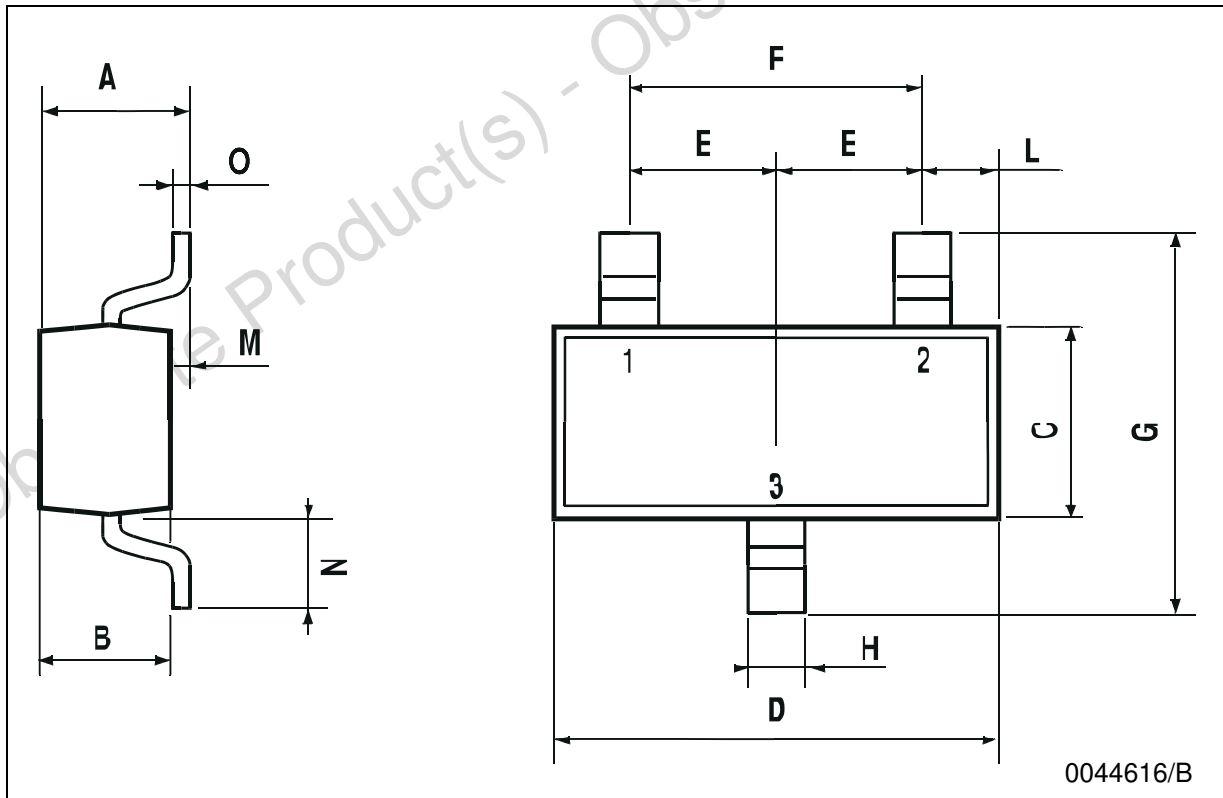
ELECTRICAL CHARACTERISTICS ($T_{case} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current ($I_E = 0$)	$V_{CB} = 20\text{ V}$ $V_{CB} = 20\text{ V}$ $T_C = 150^{\circ}\text{C}$			100 5	nA μA
I_{EBO}	Emitter Cut-off Current ($I_E = 0$)	$V_{EB} = 5\text{ V}$			100	nA
$V_{(BR)CEO}^*$	Collector-Emitter Breakdown Voltage ($I_B = 0$)	$I_C = 10\text{ mA}$	45			V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = 500\text{ mA}$ $I_B = 50\text{ mA}$			0.7	V
$V_{BE(on)}^*$	Base-Emitter On Voltage	$I_C = 500\text{ mA}$ $V_{CE} = 1\text{ V}$			1.2	V
h_{FE}^*	DC Current Gain	$I_C = 100\text{ mA}$ $V_{CE} = 1\text{ V}$ for BC817-25 for BC817-40	160 250		400 600	
f_T	Transition Frequency	$I_C = 10\text{ mA}$ $V_{CE} = 5\text{ V}$ $f = 100\text{ MHz}$	100			MHz
C_{CBO}	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = 10\text{ V}$ $f = 1\text{ MHz}$		8		pF

* Pulsed: Pulse duration = $300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

SOT-23 MECHANICAL DATA

DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.85		1.1	33.4		43.3
B	0.65		0.95	25.6		37.4
C	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
E	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
H	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8		23.6
M	0		0.1	0		3.9
N	0.3		0.65	11.8		25.6
O	0.09		0.17	3.5		6.7



Obsolete Product(s) - Obsolete Product(s)

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